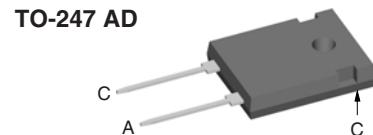
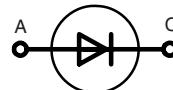


Fast Recovery Diode

SONIC-FRD™ series

I_{FAVM} = 40 A
V_{RRM} = 1800 V
t_{rr} = 100 ns

V _{RSM} V	V _{RRM} V	Type
1800	1800	DH 40-18A



A = Anode, C = Cathode

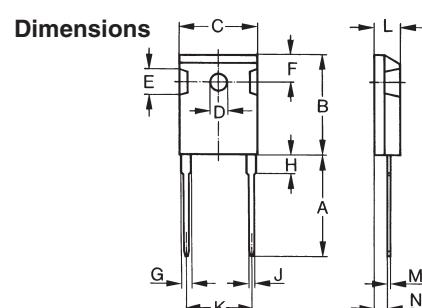
Symbol	Conditions	Maximum Ratings		
I _{FRMS}	T _{VJ} = T _{VJM}	70		A
I _{FAVM}	T _C = 85°C; rectangular, d = 0.5	40		A
I _{FRM}	t _p < 10 µs; rep. rating, pulse width limited by T _{VJM}	500		A
I _{FSM}	T _{VJ} = 45°C; t _p = 10 ms (50 Hz), sine	350		A
E _{AS}	T _{VJ} = 25°C; non-repetitive I _{AS} = tbd A; L = 100 µH	tbd	mJ	
I _{AR}	V _A = 1.5·V _R typ.; f = 10 kHz; repetitive	tbd		A
T _{VJ}		-40...+150		°C
T _{VJM}		150		°C
T _{stg}		-40...+150		°C
P _{tot}	T _C = 25°C	280		W
M _d	Mounting torque	0.8...1.2	Nm	
Weight		6		g

Symbol	Conditions	Characteristic Values		
		typ.	max.	
I _R	T _{VJ} = 25°C V _R = V _{RRM} T _{VJ} = 125°C V _R = V _{RRM}	50 1.2	100 mA	µA
V _F	I _F = 40 A; T _{VJ} = 125°C T _{VJ} = 25°C	2.4 2.4		V
V _{T0}	For power-loss calculations only	2.0		V
r _T	T _{VJ} = T _{VJM}	18		mΩ
R _{thJC}		0.45		K/W
R _{thCH}		0.25		K/W
t _{rr}	I _F = 60 A; -di/dt = 400 A/µs; V _R = 1200 V;	100		ns
I _{RM}	T _{VJ} = 25°C	30		A
S	t _b / t _a	tbd		
RSF	di _F /dt / di _R /dt	tbd		
t _{rr}	I _F = 60 A; -di/dt = 400 A/µs; V _R = 1200 V;	250		ns
I _{RM}	T _{VJ} = 125°C	40		A
S	t _b / t _a	tbd		
RSF	di _F /dt / di _R /dt	tbd		

Data according to IEC 60747

IXYS reserves the right to change limits, test conditions and dimensions

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Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	19.81	20.32	0.780	0.800
B	20.80	21.46	0.819	0.845
C	15.75	16.26	0.610	0.640
D*	3.55	3.65	0.140	0.144
E	4.32	5.49	0.170	0.216
F	5.4	6.2	0.212	0.244
G	1.65	2.13	0.065	0.084
H	-	4.5	-	0.177
J	1.0	1.4	0.040	0.055
K	10.8	11.0	0.426	0.433
L	4.7	5.3	0.185	0.209
M	0.4	0.8	0.016	0.031
N	1.5	2.49	0.087	0.102